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## [4757]-1043

S.E. (E\&TC/Electronics) (I Sem.) EXAMINATION, 2015

## ELECTRONIC DEVICES AND CIRCUITS <br> (2012 PATTERN)

Time : Two Hours
Maximum Marks : 50
N.B. :- (i) Attempt Q. No. 1 or Q. No. 2, Q. No. 3 or Q. No. 4, Q. No. 5 or Q. No. 6, Q. No. 7 or Q. No. 8.
(ii) Neat diagrams must be drawn wherever necessary.
(iii) Figures to the right indicate full marks.
(iv) Use of calculator is allowed.
(v) Assume suitable data if necessary.

1. (a) List the sources of instability of collector current. Explain selfbias circuit in detail.
(b) The transistor in the given circuit is connected as a common emitter amplifier. Calculate $\mathrm{A}_{\mathrm{v}}, \mathrm{R}_{\mathrm{i}}, \mathrm{R}_{\mathrm{o}}$. Refer Fig. 1. Assume $h_{i e}=1.1 \mathrm{k} \Omega, h_{f e}=50, h_{r e}=2.5 \times 10^{-4}$, $h_{o e}=1 / 40 \mathrm{k}$.


Fig. 1
P.T.O.

## Or

2. (a) Write a short note on thermal runaway. Explain thermal stability.
(b) Describe the method to increase the input resistance using Darlington connection.
[6]
3. (a) Draw and explain hybrid- $\pi$ common emitter transistor model.
(b) In Colpitts oscillators $\mathrm{L}_{2}=5 \mu \mathrm{H}, \mathrm{C}_{1}=\mathrm{C}_{2}=0.001 \mu \mathrm{~F}$. What will be the frequency of oscillations. If value of inductor is doubled what will be frequency of oscillations ? What should be the value of inductor to get frequency double to that of original frequency ?
[6]

## Or

4. (a) For three stage RC coupled amplifier overall upper 3 dB frequency is 16 kHz and overall lower 3 dB frequency is 25 Hz . What are the values of $\mathrm{F}_{\mathrm{L}}$ and $\mathrm{F}_{\mathrm{H}}$ for each stage ? Assume all stages identical. Also calculate bandwidth of each stage.
(b) Draw and explain various topologies of negative feedback. [6]
5. (a) What is cross over distortion ? Describe a method to minimize this distortion.
(b) A class-A amplifier operates from $\mathrm{V}_{\mathrm{CC}}=20 \mathrm{~V}$, draws a no signal current of 5 Amp and feeds a load of $40 \Omega$, through a step up transformer of $\frac{\mathrm{N}_{2}}{\mathrm{~N}_{1}}=3.16$. Find :
(i) Whether the amplifier is properly matched for maximum power transfer ?
(ii) Maximum a.c. signal power output.
(iii) Maximum d.c. power input.
(iv) Conversion efficiency at maximum signal input.

## Or

6. (a) Draw and explain complementary symmetry class-B power amplifier.
(b) A power amplifier supplies 3 watt to a load of $6 \mathrm{k} \Omega$. The zero signal d.c. collector current is 55 mA and the collector current with signal is 60 mA . How much is the percentage second harmonic distortion ?
7. (a) Explain the following non-ideal current voltage characteristics of MOSFET :
(i) Body effect
(ii) Temperature effects
(iii) Breakdown effects.
[6]
(b) Calculate the drain current and drain to source voltage of a common source circuit with an N-channel EMOSFET shown in Fig. 2. Find the power dissipated in the transistor. Given $\mathrm{V}_{\mathrm{TN}}=1 \mathrm{~V}$ and $\mathrm{K}_{n}=0.1 \mathrm{~mA} / \mathrm{V}^{2}$.


Fig. 2

## Or

8. (a) Determine the small signal voltage gain for a CS amplifier shown in Fig. 3. Transistor parameters are $\mathrm{V}_{\mathrm{TN}}=2 \mathrm{~V}$, $\mathrm{K}_{n}=0.5 \mathrm{~mA} / \mathrm{V}^{2}$ and $\lambda=0$. Assume the transistor is biased such that $\mathrm{I}_{\mathrm{DQ}}=0.4 \mathrm{~mA}$.


Fig. 3
(b) Write a short note on Bi-CMOS technology.

